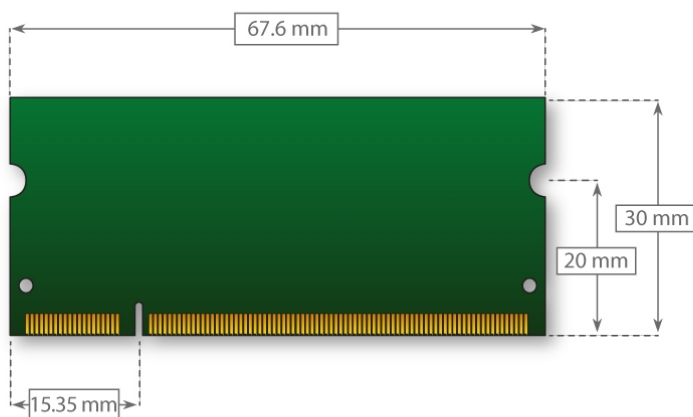


DRAM MEMORY MODULE SPECIFICATION

- > Lifetime Warranty
- > Delivered in Anti-Static Packaging



INTEGRAL Part Number	IN1V512NQEBX
Description	512MB DDR 266MHz NOTEBOOK NON-ECC MEMORY MODULE
Category	NOTEBOOK
Form Factor	200pin SoDIMM
Density	512MB
DRAM Technology	DDR
Speed	PC2100 / 266 MHz
Depth	64Mbit
Width	X64bit
Buffering	UNBUFFERED
Error Correction	NON-ECC
CAS Latency	2.5 CYCLES
Voltage	2.5 V
Rank	2
Profile	STANDARD
DRAM IC Configuration	32Mbit X 16bits
DRAM IC Count	8 Chips
DRAM IC Package	TSOP
DRAM IC Placement	DOUBLE SIDED
Note	